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# Co-Design and Validation Approach for Beam-Steerable Phased Arrays of Active Antenna Elements with Integrated Power Amplifiers

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**Abstract**—An approach for designing a beam-steering active phased array of antenna elements with integrated power amplifiers (PAs) is presented. It is based on an amplifying active integrated unit cell (AiUC) concept, where the AiUC comprises a radiating slot element, a GaN high electron mobility transistor (HEMT), its input matching and DC biasing/feeding circuitry. The HEMT is embedded in the antenna element, being directly impedance-matched to HEMT’s drain output, i.e. without using any intermediate and potentially lossy impedance matching network. The proposed co-design approach involves a full-wave analysis of the AiUC passive part (naturally including elements mutual coupling effects) along with the subsequent full-system harmonic balance simulations. Furthermore, we extend the standard definition of the scan element pattern (SEP) to the *active* scan element pattern (ASEP) that accounts for non-linear effects of PAs on AiUC performance. We show that the ASEP is, in general, power-dependent and has a different shape as compared to the SEP. The proposed approach has been demonstrated for a K-band AiUC design example. It was verified through an active waveguide simulator, which is equivalent to the 23.7° H-plane beam-steering case. Measurements are in good agreement with simulations, revealing AiUC 47% peak drain efficiency and 33 dBm maximum radiated power. The predicted scan range is  $\pm 60^\circ$  and  $\pm 37^\circ$  in the E- and H-plane, respectively.

**Index Terms**—active antenna, array antenna, beam steering

## I. INTRODUCTION

Amplifying active integrated antenna (AiA) designs have been widely studied [1], [2], where the antenna typically represents an integrated combination of a radiating element and an active device (power amplifier, PA). These designs can provide high radiated power, high power efficiency, and compact size, as compared to conventional active antenna implementations. The benefits of AiAs become more noticeable and vital for millimeter-wave (mm-wave) frequency applications, where

dissipative losses of printed transmission lines and antenna-PA interconnections can be severe. The state-of-the-art in mm-wave AiA systems covers several design implementations. In [3]–[6], a PA is combined with an antenna element either on a single printed circuit board (PCB) or within a PCB assembly to maximize power efficiency and radiated power at S-/C-bands. This approach is, however, not well suited for higher frequencies, due to the increasing power losses of matching circuits and harmonic filters introduced between the PAs and antennas. To overcome this problem, direct impedance matching between the PA and radiating element can be used, as was demonstrated in [7], [8] for PCB-based designs and [9] for the antenna-in-package architecture. Monolithic microwave integrated circuits (MMICs) is a popular alternative, offering compact design and high repeatability (see [10], [11]). A common drawback is low radiation efficiency of usually narrowband on-chip antennas, especially at mm-wave frequencies.

The above-described enhancements have been demonstrated using rather conventional antenna integration approaches, where the radiator has a well-defined excitation port that is interconnected with an active device through intermediate circuitry. Further increasing the integration density is possible [12]–[14], e.g., by embedding active components inside the radiator and impedance matching it directly to the optimum PA load impedance. The optimum PA load impedance is commonly defined for the maximum power efficiency or maximum gain and is generally complex-valued, hence rather different from the standard 50  $\Omega$ . Recently, this concept of direct integration and impedance matching was reported in [15] for a K-band GaN high electron mobility transistor (HEMT)-integrated cavity-backed slot antenna. This antenna, as well as all the above-mentioned AiAs, has been designed as an isolated element, hence without considering the effects of antenna mutual coupling and nonlinearity of PAs in arrays of such AiA elements. Nevertheless, the considered direct integration approach can be further extended to the development of active integrated array antennas (AiAAs). Such AiAAs are potentially capable of providing a wide-angle 2D (full-space) beam-steering range with high effective isotropic radiated power. The design of an active integrated element for array antenna applications is a significant challenge. In this work, we will refer this element to as an active integrated unit cell (AiUC). It should be noted that different designs of amplifying AiAAs have been previously considered [3], [16]–[20]. In [16]

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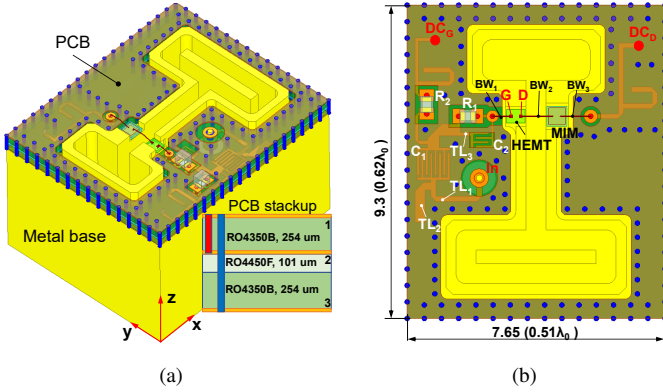


Fig. 1. The AiUC configuration: (a) perspective view (the PCB stackup is given in the inset), (b) top view (all dimensions are in mm).

and [18], an integrated  $2 \times 2$  MMIC sub-array at Q-band and a fixed-beam C-band AiAA were reported, respectively, where the radiator and the PA are physically separated with the  $50\text{-}\Omega$  interstage impedance matching networks. Another concept was presented in [20], where a unified deep-integrated AiA was used in a 1D amplifier-circuit-antenna array. This concept fully obviates the need in any input/output matching circuitry. Unfortunately, it is currently applicable only to the series-fed 1D AiAs with minor beam steering.

This paper presents a further development of the work in [15] towards wide-angle 2D beam-steerable AiAAs of AiUCs. We focus on the AiUC in the infinite array environment that leads to the antenna element design for large-scale AiAAs. The key novel contributions are three-fold: (i) an AiUC co-design methodology based on the infinite array electromagnetic (EM)-circuit co-simulations and a new AiUC beam-steering performance metric, referred to as an *active* scan element pattern (ASEP), which jointly account for the antenna mutual coupling and nonlinear effects of PAs in the array design process; (ii) an AiUC design example with an embedded GaN HEMT at K-band, optimized through the proposed co-design methodology; (iii) an experimental validation setup for the AiUC that is based on a two-element active waveguide simulator concept. Its performance is equivalent to the  $23.7^\circ$  H-plane beam-steering infinite array case and is used to extract the ASEP.

The paper is organized as follows. Section II presents the proposed co-design approach through an example AiUC. The ASEP is defined in Section III. Section IV addresses the design of the two-element active waveguide simulator. Section V provides results discussion and comparison with prior-art. Finally, the conclusions are formulated in Section VI.

## II. CO-DESIGN APPROACH FOR AN AiUC

### A. AiUC Description

The AiUC was developed for a planar uniform array with a rectangular lattice at the central frequency of  $f_0 = 20$  GHz. Its 3D view is given in Fig. 1. This AiUC takes the element type in [15] as the starting point, where we have introduced several significant modifications to make the design suitable for beam-steering array applications, i.e. to optimally perform in the presence of antenna elements mutual coupling and nonlinear

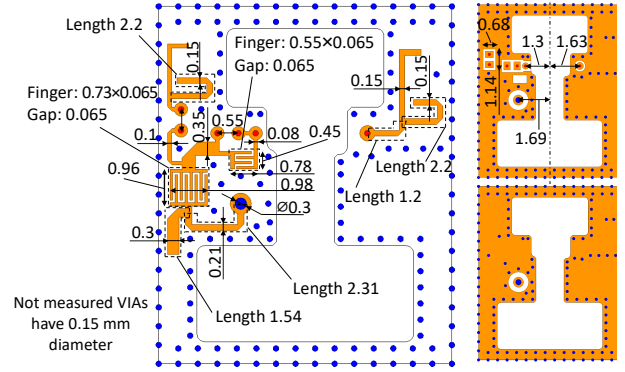


Fig. 2. PCB layers topologies with main design dimensions (in mm): left – enlarged layer 2 (inner), top right – layer 1 (top), bottom right – layer 3 (bottom). Layer numbers are given in Fig. 1(a). Through vias (blue) connect all PCB layers; blind vias (red) connect layer 1 and layer 2.

effects of PAs. Another important aspect is to make it suitable for the verification through the active waveguide simulator approach as detailed in Section IV.

The AiUC comprises the brass base which supports the 3-layer PCB. The asymmetrical H-shaped cavity-backed slot radiator is milled in the base. The lower  $y$ -oriented slot segment [Fig. 1(b)] incorporates the ridge element to increase the equivalent slot electrical length while preserving its overall dimensions. The straight  $x$ -oriented slot segment gives the major contribution to the radiated field defining the radiation resistance, whereas the  $y$ -oriented parts contribute to the antenna reactance. The slot element has  $xz$ -plane symmetry, which provides a well-defined polarization plane ( $yz$ -plane). A HEMT is mounted directly at the slot edge [Fig. 1(a)]. Its gate port is connected via the bondwire  $BW_1$  to the PCB. The bondwire  $BW_2$  transversely crosses the slot and connects the HEMT's drain to the shunt  $2.2\text{-pF}$  MIM capacitor (Teclia BMS2R2J1K), thus directly exciting the radiating element. The drain DC feed is applied via the bondwire  $BW_3$ . In this design, as well as in [15], we employed the GaN HEMT TGF2942 from Qorvo. Moving the HEMT along the  $x$ -axis we can effectively tune the antenna impedance visible from the drain side. The PCB stackup is given in the inset of Fig. 1(a). The PCB is formed by two  $254\text{-}\mu$  thick Rogers RO4350B cores bounded by  $101\text{-}\mu$ m thick Rogers RO4450F prepreg. The topologies of the three conducting layers are detailed in Fig. 2. The AiUC is excited through the  $50\text{-}\Omega$  orthogonal coaxial assembly ( $2.92$  mm connector 1014-21SF with 1090-11G launching pin from Southwest). Two stripline segments  $TL_1$  and  $TL_2$  [Fig. 1(b)] form the input matching circuit connected to the eight-fingers interdigital DC blocking capacitor  $C_1$ . The gate stabilization resistor  $R_1 = 50\ \Omega$  is connected in parallel with the combination of  $TL_3$  cascaded with the four-finger interdigital capacitor  $C_2$ . This circuit is tuned to have the series resonance at  $f_0$ . The equivalent AiUC input circuit representation is, in general, similar to the one given in [15]. An additional high-frequency resistor  $R_2 = 25\ \Omega$  was introduced inside the gate biasing line to improve the low-frequency AiUC stability. Apart from this, the important distinction with the design from [15] is the input circuitry shielding realized by the metallization of the top PCB layer.

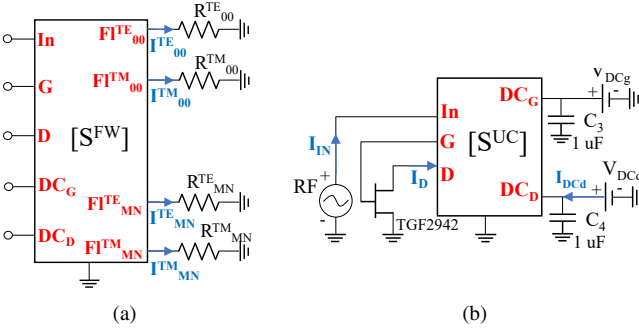


Fig. 3. (a) The 5-port  $S$ -matrix  $S^{UC}$  derived from  $S^{FW}$  by the Floquet modal ports termination.  $S^{FW}$  is computed using the 3D full-wave model (Fig. 1). (b) Circuit diagram of the harmonic balance co-simulation setup.

The AiUC transverse dimensions are  $d_x = 0.62\lambda_0$ ,  $d_y = 0.51\lambda_0$ , where  $\lambda_0$  is the free-space wavelength corresponding to  $f_0$ . This allows having the grating lobes-free beam-steering regime up to  $74^\circ$  in the E-plane ( $yz$ -plane) and up to  $38^\circ$  in the H-plane ( $xz$ -plane).

### B. Co-Design Methodology

The proposed AiUC comprises both linear (passive) and nonlinear (active) parts. The AiUC nonlinear effects become significant when the HEMT is driven with a large input signal and operates in class-AB [21], which is the case when both high efficiency and linearity are required. A combined circuit-EM co-simulation approach was developed to analyze the AiUC. The linear passive AiUC part was simulated in Ansys HFSS. The five AiUC ports are depicted in Fig. 1(b):  $I_n$  (coaxial input),  $G$  (HEMT gate),  $D$  (HEMT drain),  $DC_G$  (gate DC biasing),  $DC_D$  (drain DC feeding). Since the HEMT is electrically small, we assume that its interaction with the PCB circuitry and radiating structure can be correctly described through two lumped ports  $G$  and  $D$ . The model sidewalls boundary conditions were set to periodic, and the Floquet port was introduced at 30 mm above the AiUC. Thus, all array elements mutual coupling effects are naturally included through the AiUC boundary conditions. The Floquet port contains  $N_F$  modes, which represent Floquet  $TE_{mn}$  and  $TM_{mn}$  modes, where  $m, n$  are modal indices [22]. This EM model provides the  $S$ -matrix  $S^{FW}$  that fully describes all interactions inside the linear AiUC part. Next,  $S^{FW}$  is transferred to Keysight ADS environment, where it is reduced to the 5-port  $S$ -matrix  $S^{UC}$  by terminating the Floquet modal ports with matched loads  $R_{mn}^{TE/TM}$  [Fig. 3(a)].

Next, the 5-port  $S^{UC}$  was used in the ADS harmonic balance (HB) simulator according to the setup in Fig. 3(b). The applied DC conditions are:  $V_{DCg} = -2.4$  V,  $V_{DCd} = 28$  V,  $I_{DCd} = 35$  mA. The HB convergence has been reached with the first three harmonics, hence the full-wave analysis of the AiUC was performed up to  $3f_0$ . For accurate analysis, the Floquet port includes all modes that can propagate for the full hemispherical beam-steering sector at  $3f_0$ . This results in  $N_F = 30$ , and  $S^{FW}$  represents the 35-port  $S$ -matrix.

During beam steering,  $S^{FW}$  changes for each beam direction  $(\theta_s, \varphi_s)$ , where  $\theta_s, \varphi_s$  are elevation and azimuth beam-steering angles, respectively. To speed up the simulations,

a unified control environment was developed in MATLAB using MATLAB-HFSS and MATLAB-ADS interfaces. The following AiUC characteristics are obtained from the co-simulation process: active drain impedance and reflection coefficient  $Z_D, \Gamma_D$ ; active input impedance and reflection coefficient  $Z_{in}, \Gamma_{in}$ ; transducer and available co- and cross-polarized power gains  $G_T^{c/x}, G_P^{c/x}$ ; drain power efficiency  $\eta_D$ . It is worth noting that power gains are computed using power of the dominant Floquet modes ( $P_{00}^{c/x}$ ) related to co- and cross-polarized components:

$$G_T^{c/x} = P_{00}^{c/x} / P_{avs}, \quad G_P^{c/x} = P_{00}^{c/x} / P_{in}, \quad (1)$$

where  $P_{avs}$  and  $P_{in} = P_{avs}(1 - |\Gamma_{in}|^2)$  are the available from the source and input powers, respectively [21]. For each AiUC port, a reference impedance  $Z_0$  can be, in general, complex [23]. The designations of all branch currents and nodal voltages can be found in Fig. 3(a) and Fig. 3(b).

The AiUC co-design aims at the maximum power efficiency by optimizing the HEMT loading conditions. The optimum HEMT drain impedance  $Z_{Dopt} = 17 + j46 \Omega$  was reported in [15] based on the load-pull analysis. Note that this value is not equal to the impedance  $Z_{Dconj} = 11 + j44 \Omega$  providing the drain conjugate match. At the same time, the AiUC input 50- $\Omega$  port should be matched with the HEMT input impedance from the gate side  $Z_{Tg} = 3 - j13.2 \Omega$ . Owing to the shielding of the input circuitry, at the first design stage the input matching circuit and the radiating slot structure can be tuned independently to provide  $S_{D,D}^{FW} = \Gamma_{Dopt}$  and  $S_{G,G}^{FW} = \Gamma_{Gopt}$ , where  $\Gamma_{Dopt}$  and  $\Gamma_{Gopt}$  correspond to  $Z_{Dopt}$  and  $Z_{Tg}^*$ . Next, the obtained  $S^{FW}$  is used in the HB simulator. The final AiUC structure optimization is performed iteratively.

The AiUC was optimized according with the proposed co-design methodology for the broadside beam. The main final AiUC structure parameters are:  $x$ -oriented slot segment —  $0.3 \times 0.04 \times 0.34 \lambda_0^3$ ; upper  $y$ -oriented slot segment —  $0.08 \times 0.21 \times 0.34 \lambda_0^3$ ; lower segment —  $0.11 \times 0.32 \times 0.34 \lambda_0^3$ ; ridge —  $0.027 \times 0.24 \times 0.34 \lambda_0^3$ ; HEMT shift relative to the AiUC center —  $0.09 \lambda_0$ . The slot is allocated inside the AiUC in such a way that its edges are equally spaced from the AiUC  $x$ -boundaries. The main PCB dimensions are presented in Fig. 2.

### C. Broadside Performance

The broadside AiUC performance was studied first by assigning  $(\theta_s, \varphi_s) = (0, 0)$ . Simulated AiUC small-signal characteristics are presented in Fig. 4(a). The peak  $G_T^c = 8.4$  dB, whereas the relative cross-polarization level is below  $-30$  dB. The simple 2-element matching circuit provides a relatively narrowband matching with almost pure reactive HEMT input. As a result, the 3-dB  $G_T^c$  bandwidth is 540 MHz. However, the  $G_P^c$  curve indicates a wider available gain bandwidth of 820 MHz.

Next, we explored the large-signal performance within the  $20 \pm 0.25$  GHz bandwidth by sweeping  $P_{avs}$  in the  $-10 \dots 35$  dBm range. Fig. 4(b) demonstrates simulated  $\Gamma_D$  at fundamental and harmonics frequencies. As expected,  $\Gamma_D$  does not depend on  $P_{avs}$  due to the small coupling between the AiUC radiating parts and the input circuitry. The results

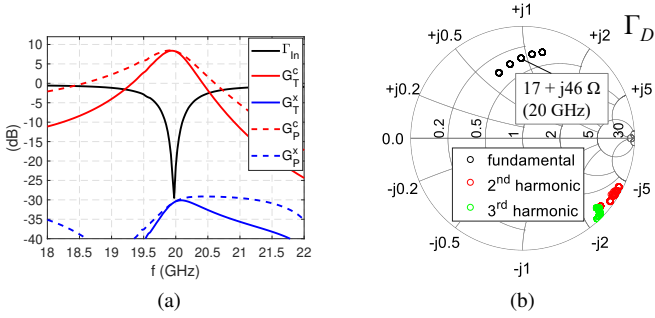


Fig. 4. (a) Simulated small-signal performance of the AiUC in the broadside regime; (b) Simulated active drain reflection coefficient  $\Gamma_D$  at fundamental ( $20 \pm 0.25$  GHz, 0.125 GHz step) and harmonic frequencies.  $P_{avs} = -10 \dots 35$  dBm.  $Z_0 = 50 \Omega$ .

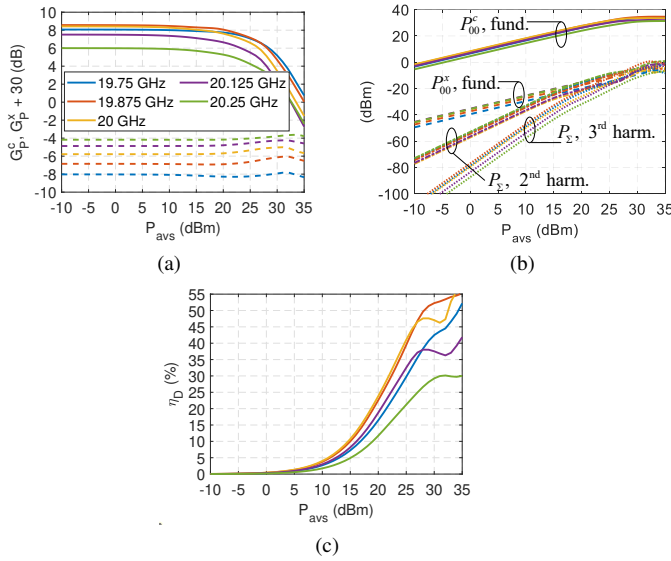


Fig. 5. Simulated large-signal broadside performance of the AiUC in the infinite array environment. (a) co- (solid lines) and cross-polarized (dashed lines) power gain of the AiUC; (b) radiated power at fundamental and harmonic frequencies for co- and cross-polarized components separately, and full radiated power ( $P_\Sigma$ ) at the second and third harmonics; (c) drain efficiency.

evidence that the targeted  $Z_{Dopt}$  was achieved at  $f_0$ , while  $\Gamma_D$  amounts to  $0.97 \exp(-j32^\circ)$  and  $0.97 \exp(-j44^\circ)$  at  $2f_0$  and  $3f_0$ , respectively. Maximum  $\eta_D = 59\%$  can be theoretically realized with such harmonic terminations.

The gain performance is depicted in Fig. 5(a) for both co- and cross-polarized components. The 1-dB compression point at 20 GHz is  $P_{1dB} = 21$  dBm. Fig. 5(b) demonstrates the radiated powers at fundamental and harmonic frequencies. Each harmonic power  $P_\Sigma$  was computed by summing the power of all propagating Floquet modes. The simulated  $\eta_D$ , presented in Fig. 5(c), predicts achievable 47% for  $P_{avs} = 27$  dBm at 20 GHz.

### III. BEAM-STEERING PERFORMANCE OF THE AiUC

In the analysis of AiUCs, the radiating structure and the active component are closely integrated, with no well-defined “antenna port”. This makes it difficult to characterize the radiating and active AiUC parts separately. Therefore, a new AiUC performance metric taking into account all the effects

occurring in the integrated antenna-PA structure during beam steering is proposed.

#### A. Active Scan Element Pattern of the AiUC

The derivation of the classical scan element pattern (SEP) employs either the superposition [22], [24] or the reciprocity principle [25], but neither can be applied to the AiUC due to its nonlinear and nonreciprocal nature. The former property leads to a beam-steering performance dependence on the AiUC input power. Strictly speaking, for the AiUC we cannot introduce the standard SEP, which represents a far field of a single excited array element, while all other elements are terminated with matched loads. This is because in a nonlinear operation regime the full AiAA radiated field, in general, cannot be represented as a superposition of partial fields from separately excited AiUCs. Nevertheless, we still can characterize the radiation performance of the AiUC employing its equivalent power-dependent ASEP. To get the desired ASEP, let us consider the transverse electromagnetic field ( $\mathbf{E}, \mathbf{H}$ ) at  $f_0$  on the  $xy$ -plane at  $z = z_0$  above the infinite AiAA aperture:

$$\mathbf{E} = \sum_{(m,n)} A_{mn}^{TE} \mathbf{E}_{mn}^{TE} + \sum_{(m,n)} A_{mn}^{TM} \mathbf{E}_{mn}^{TM}. \quad (2)$$

$$\mathbf{H} = \sum_{(m,n)} A_{mn}^{TE} \mathbf{H}_{mn}^{TE} + \sum_{(m,n)} A_{mn}^{TM} \mathbf{H}_{mn}^{TM}, \quad (3)$$

where  $\mathbf{E}_{mn}^{TE/TM}$ ,  $\mathbf{H}_{mn}^{TE/TM}$  are electric and magnetic field vectors of TE and TM Floquet modes [22];  $A_{mn}^{TE/TM}$  are constant modal amplitudes that depend only on  $(\theta_s, \varphi_s)$  and  $P_{avs}$ . The detailed description of the modal fields is given in Appendix A. Note that for the chosen modal normalization (A.1), (A.2)  $|A_{mn}^{TE/TM}|^2/2 = P_{mn}^{TE/TM}$ .

The infinite array far field will still represent the superposition of the propagating Floquet modes (2), (3) with  $A_{mn}^{TE/TM}$  multiplied by the corresponding phase factors. However, we will use another representation, introducing equivalent electric  $\mathbf{J}_{mn}^{TE/TM} = \mathbf{z}^0 \times \mathbf{H}_{mn}^{TE/TM}$  and magnetic  $\mathbf{M}_{mn}^{TE/TM} = -\mathbf{z}^0 \times \mathbf{E}_{mn}^{TE/TM}$  surface currents, where  $\mathbf{z}^0$  is the  $z$ -axis unit vector. Next, employing the far-field representation through the radiation integrals [26], we arrive at  $\mathbf{E}_{FFmn}^{TE/TM}$ :

$$\mathbf{E}_{FFmn}^{TE/TM}(\mathbf{r}) = A_{mn}^{TE/TM} \mathbf{C}_{mn}^{TE/TM} \frac{\exp(-jkr)}{4\pi r} I_{mn}(\theta, \varphi), \quad (4)$$

where  $\mathbf{r}$  is the radius vector of the field observation point with spherical coordinates  $(r, \theta, \varphi)$ . The derivation of (4) and definition of  $\mathbf{C}_{mn}^{TE/TM}$  are detailed in Appendix A. The term  $I_{mn}$  has the following form:

$$I_{mn}(\theta, \varphi) = S \text{sinc}\left(\left(k_x - k_{xm}\right) \frac{d_x}{2}\right) \text{sinc}\left(\left(k_y - k_{ym}\right) \frac{d_y}{2}\right) \times \sum_{q=-\infty}^{\infty} \sum_{p=-\infty}^{\infty} e^{j(k_x - k_{x0})pd_x + j(k_y - k_{y0})qd_y}, \quad (5)$$

where  $k_x = k \sin(\theta) \cos(\varphi)$ ,  $k_y = k \sin(\theta) \sin(\varphi)$ , and  $S = d_x d_y$  is the AiUC area. The double summation in (5) is the array factor (AF) with the beam-steering direction  $(\theta_s, \varphi_s)$ . It can be written as [22]

$$AF(\theta, \varphi) = \frac{4\pi^2}{S} \sum_{q=-\infty}^{\infty} \sum_{p=-\infty}^{\infty} \delta(k_x - k_{xp}) \delta(k_y - k_{yq}). \quad (6)$$

In (6), the Dirac delta functions evidence that the AiAA radiates in the discrete number of angular directions, which was expected from (2), (3). During beam steering, the direction of interest is  $(\theta_s, \varphi_s)$ , i. e.  $k_x = k_{x0}$ ,  $k_y = k_{y0}$  (Appendix A). With this substitution into (4), we can notice that only  $I_{00}$  is non-zero, and  $C_{00\theta}^{TE} = C_{00\varphi}^{TM} = 0$ . Then, separating the AF in (4), we extract the contribution to the AiAA far field from a single AiUC ( $\mathbf{E}_a$ ), *operating inside the fully excited (with a given  $P_{avs}$ ) array environment*:

$$\mathbf{E}_a(r, \theta_s, \varphi_s) = j \frac{\sqrt{\eta S \cos(\theta_s)}}{\lambda} (A_{00}^{TM} \boldsymbol{\theta}^0 - A_{00}^{TE} \boldsymbol{\varphi}^0) \frac{e^{-jkr}}{r}, \quad (7)$$

where  $\eta = 120\pi \Omega$  is the free-space wave impedance;  $\boldsymbol{\theta}^0$  and  $\boldsymbol{\varphi}^0$  are the  $\theta$ - and  $\varphi$ -axis unit vectors, respectively. The angular dependence of  $\mathbf{E}_a$  gives us the desired vector field ASEP. We now define the vector gain ASEP of the AiUC ( $\mathbf{G}_a$ ) following the standard definition of realized gain. Recalling that  $A_{00}^{TE/TM}$  depends on  $P_{avs}$  and changing  $(\theta_s, \varphi_s)$  to  $(\theta, \varphi)$ , we can express the gain ASEP in the following form

$$\mathbf{G}_a(\theta, \varphi, P_{avs}) = \frac{4\pi S \cos(\theta)}{\lambda^2} (G_T^\theta(\theta, \varphi, P_{avs}) \boldsymbol{\theta}^0 + G_T^\varphi(\theta, \varphi, P_{avs}) \boldsymbol{\varphi}^0). \quad (8)$$

We can point out that the introduced ASEP comprises the AiUC transducer gains  $G_T^{\theta/\varphi} = P_{00}^{TM/TE}/P_{avs}$ , which are related to the amplifying property of the integrated PA, and the remaining part, similar to the standard SEP of a passive unit cell (UC) [22], related to the radiating element itself. Thus, the ASEP naturally incorporates both traditional antenna and PA effects. The latter includes PA gain compression and sensitivity to the load variation. It is the ASEP that should be used when the active gain  $\mathbf{G}_{AA}$  of a large (negligible edge effects) AiAA of  $N$  AiUCs to be computed, i.e.  $\mathbf{G}_{AA} = N\mathbf{G}_a$  [24].

### B. Simulation Results

The AiUC performance at  $f_0$  for beam steering in the E- and H-planes is presented first. In Fig. 6(a), the co-polarized ASEPs are demonstrated for different  $P_{avs}$ :  $-10$  dBm (linear regime) and  $27$  dBm (2.5-dB compression). The conventional SEP of the passive UC radiating part is given for reference and defined as in [22]:

$$\mathbf{G}_{UC}(\theta, \varphi) = \frac{4\pi S \cos(\theta)}{\lambda^2} (|S_{TM00,D}^{FW'}|^2 \boldsymbol{\theta}^0 + |S_{TE00,D}^{FW'}|^2 \boldsymbol{\varphi}^0), \quad (9)$$

where we employed renormalized transmission coefficients from the drain port to  $TE_{00}$  and  $TM_{00}$  Floquet modes. The renormalized  $S$ -matrix  $S^{FW'}$  was computed from  $S^{FW}$  [27] with the following port reference impedances replacement  $\{D, G, DC_D, DC_G\} = \{17 - j46, 3 - j13.2, 0.5, 0.5\} \Omega$ . The PA gain compression can be seen in 6(a) as the variation of the ASEP peak level. In the E-plane, the scan blindness

nearby the appearance of the array grating lobe at  $\theta \approx 73^\circ$  is observed. Meanwhile, the H-plane beam steering does not lead to scan blindness. It is useful to examine the normalized  $G_T^c$  and  $S_{TE/TM00,D}^{FW'}$ , to understand the AiUC behavior with no accounting for the cosine aperture projection effect and different gain peak levels. These results are presented in Fig. 6(b). Drain efficiency dependencies on  $\theta_s$  in the E- and H-plane are given in Fig. 6(c). We can observe that, even in the linear regime, the angular dependency of the  $G_T^c$  differs from  $S_{TE/TM00,D}^{FW'}$ . We could expect this, as the radiating element is not conjugately matched with the HEMT drain (Section II-B). As a result, e.g. during beam steering in the E-plane,  $Z_D$  quickly recedes from  $Z_{Dconj} = 11 + j44 \Omega$  [Fig. 6(c)], and  $G_T^c$  drops faster with  $\theta_s$  compared to  $S_{TM00,D}^{FW'}$ . At the same time, in the H-plane, the  $\Gamma_D$  locus is closer to the conjugately matching conditions, and thus the slopes of  $G_T^c$  and  $S_{TE00,D}^{FW'}$  curves are very close. Another important observation is that the angular shape of the ASEP depends on the power level, as can be clearly seen in Fig. 6(b). This is the result of the nonlinear HEMT behavior leading to the HEMT drain input impedance variation with  $P_{avs}$ . The two aforementioned phenomena, namely the discrepancy between SEP and ASEP angular shapes and the ASEP power-dependent nature, are the main distinctive features of the AiUC beam-steering performance as compared to the passive UC.

It is worth mentioning that  $\Gamma_{in}$  remains almost constant during beam steering owing to the decoupling of the input circuitry and the AiUC radiating elements. At the same time, the relative cross-polarization level is lower than  $-27$  dB and  $-30$  dB for the  $\pm 60^\circ$  and  $\pm 37^\circ$  beam-steering range in the E- and H-plane, respectively. The related simulation results are omitted here for compactness.

As we have shown, the AiUC beam-steering performance is power-dependent. At 2.5-dB gain compression regime, the AiUC's E-plane scan range is  $\pm 60^\circ$  with 2.1 dB  $G_T^c$  scan loss and  $\eta_D$  degradation from 47% to 25%; the H-plane scan range is  $\pm 37^\circ$  with 1.7 dB scan loss and  $\eta_D$  degradation from 47% to 37%.

## IV. EXPERIMENTAL CHARACTERIZATION

A common approach to experimentally validate array beam-steering performance is to manufacture a relatively large finite array fragment to measure the SEP and active reflection coefficient [22]. Such characterization is usually based on the superposition principle (e.g., [20]) owing to the linearity property of the system. However, as we have discussed previously, this is not applicable to AiAAs in general. The analysis of such arrays requires a full beamforming and feeding circuitry, which can realize the desired excitation of the AiAA [3], [16]. This can be complicated and costly. The waveguide (WG) simulator approach is a good alternative in this case [28]–[30]. This technique has been applied to measure array aperture reflection coefficient [28]. In other studies, the active reflection coefficient is found through the excitation of the single- [29] and multi-element [30] WG simulators, where the WG is terminated with a matched load. The novelty of the present work is the extension of the WG simulator technique to the case of nonlinear and nonreciprocal AiUCs.

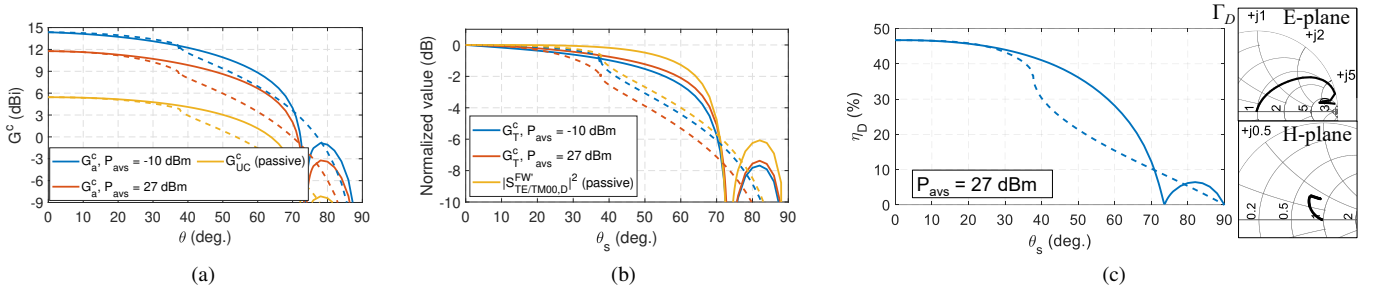


Fig. 6. (a) Simulated gain active scan element pattern (ASEP) of the full AiUC and scan element pattern (SEP) of the passive radiating part. Computed beam-steering performance of the AiUC versus  $\theta_s$ ; (b) normalized co-polarized AiUC transducer gains (1) and transmission coefficient from the drain port to the dominant Floquet modes; (c) drain efficiency. All results are given at  $f_0$  in the E- (solid lines) and H-plane (dashed lines) for different  $P_{avs}$ . Insets demonstrate  $\Gamma_D$  variations during beam steering,  $Z_0 = 17 - j46 \Omega$ .

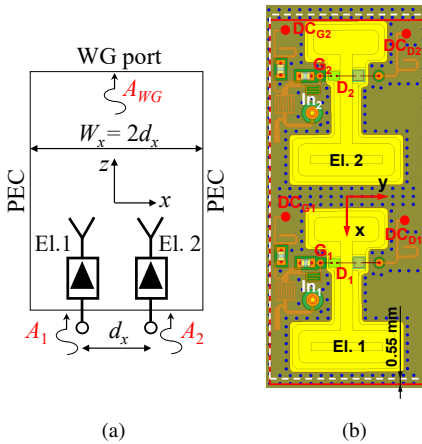


Fig. 7. (a) The scheme of the two-element H-plane active WG simulator. (b) Top view of the two-element structure inside the WG simulator. The red rectangle indicates WG border, white — geometric border of two AiUCs.

#### A. Active Waveguide Simulator Technique for AiUCs

A finite AiAA fragment is placed inside a rectangular WG and excited in such a way that it experiences the same EM conditions as the AiUC at a particular beam-steering regime in the infinite array [28]. We use a two-element H-plane active WG simulator, as schematically shown in Fig. 7(a). The WG transverse sizes are  $W_x = 2d_x$  and  $W_y = d_y$ . The following active WG simulator principles are relevant.

- 1) Each WG mode excitation can be interpreted as the simultaneous excitation of as many as 4 plane waves [28]. If the  $TE_{10}$  mode is excited, the WG simulator provides conditions equivalent to the AiUC H-plane dual-beam operation, with beam steering to  $\pm\theta_s^{WG}$ , where

$$\sin(\theta_s^{WG}) = \lambda/(4d_x). \quad (10)$$

At  $f_0$ , (10) gives  $\theta_s^{WG} = 23.7^\circ$ . We then can employ the UC symmetry property [31], resulting in  $\Gamma_{D1,2} = \Gamma_D(\theta_s = \theta_s^{WG}, \varphi_s = 0)$ , where  $\Gamma_{D1,2}$  denotes the active drain reflection coefficient of the AiUCs inside the WG.

- 2) The AiUCs should be excited with proper amplitudes  $A_{1,2}$  ( $|A_{1,2}| = \sqrt{2P_{avs1,2}}$ ) to generate the desired WG modal content. This can be formulated mathematically, considering the relations specified in paragraph 1:

$$A_i = A_{Fl} [e^{-jkx_{ci} \sin(\theta_s^{WG})} + e^{jkx_{ci} \sin(\theta_s^{WG})}], \quad (11)$$

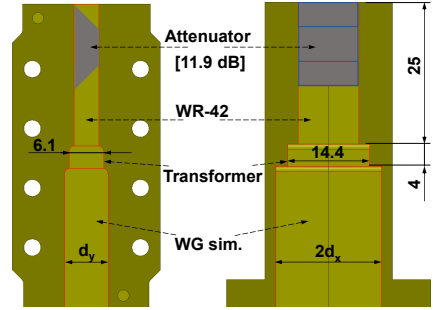


Fig. 8. E- (left) and H-plane (right) cross-sections of the WG structure used to implement the two-element WG simulator. All dimensions are in mm. Fillet radius is 1 mm.

where  $A_{Fl} = \sqrt{2P_{avs}}$  is the magnitude of the incident AiUC voltage wave, providing beam steering to  $\pm\theta_s^{WG}$ ;  $x_{ci}$  is the  $x$ -coordinate of the  $i$ -th AiUC radiation center. Substituting  $x_{c1,2} = \pm d_x/2$  [see Fig. 7(a)], we find  $A_1 = A_2 = 2A_{Fl} \cos(kd_x \sin(\theta_s^{WG})/2)$ . This result is very important since it ensures that both AiUCs will be under the same compression conditions. Next, the AiUC gains (1) at  $(\theta_s = \theta_s^{WG}, \varphi_s = 0)$  can be found through the following relations:

$$G_T^c = \frac{|A_{WG}|^2}{2|A_1|^2}, \quad G_P^c = \frac{|A_{WG}|^2}{2|A_1|^2(1 - |\Gamma_{in1}|^2)}. \quad (12)$$

Here, we assume that  $\Gamma_{in1,2}$  are similar. The rigorous derivation of (12) is given in Appendix B.

- 3) WG sidewalls positions should coincide with AiAA “planes of symmetry” (E-field null-planes) [28]. If the AiUC had been perfectly symmetric in geometry, the radiation and geometric AiUC centers would have coincided. However, the AiUC symmetry with respect to the  $yz$ -plane is slightly violated due to the different shapes of the upper and lower  $y$ -oriented slot segments [see Fig.1(b)]. As a result, the AiUC radiation center is shifted relative to its geometric center along  $x$ -axis by 0.55 mm. To realize the required field symmetry, the WG should cover the structure as shown in Fig. 7(b).

To measure the WG simulator output signal we connected it to the standard WR-42 WG interface through a quarter-wave transformer. The longitudinal cross-sections of the full WG structure are given in Fig. 8. The full WG is implemented as two identical blocks connected in the E-plane; the

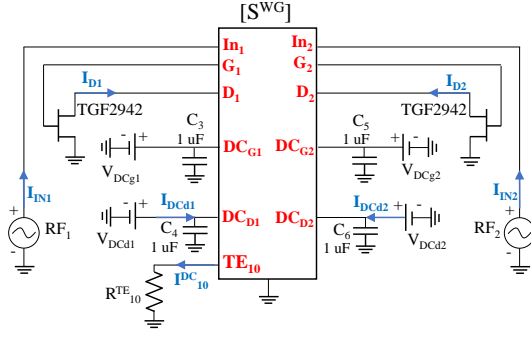


Fig. 9. Circuit diagram of the two-element WG simulator harmonic balance co-simulation setup.

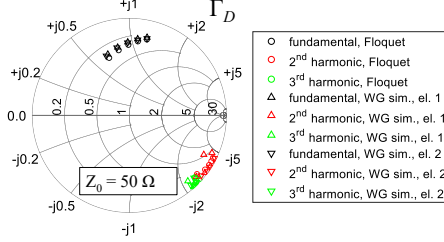


Fig. 10. Comparison of the simulated active drain reflection coefficient  $\Gamma_D$  at  $P_{avs} = -10$  dBm for: the AiUC with periodic boundary conditions for  $(\theta_s, \varphi_s) = (23.7, 0)^\circ$ , and each AiUC of the two-element WG simulator. Frequency is swept in the  $20 \pm 0.25$  GHz range with 0.125 GHz step.

WG material is brass. The transformer aims to provide the impedance matching at the fundamental frequency, but it was found to realize a decent matching performance also for the harmonics (reflection coefficient is  $-33$ ,  $-11$  and  $-16$  dB at  $f_0$ ,  $2f_0$  and  $3f_0$ , respectively). Another discrepancy with the periodic array environment is that the WG simulator, according to (10), provides different  $\theta_s^{WG}$  at harmonic frequencies. However, since the radiating slot element itself significantly suppresses harmonics radiation, it was found that both above-mentioned factors weakly affect the AiUC performance. These assumptions were verified through a co-simulation model. The passive simulator part, comprising the two-element structure covered with the WG, was simulated in HFSS. The ports of the two AiUCs are depicted in Fig. 7(b). A WG port was set at the WR-42 side. The port includes 11 modes propagating at  $3f_0$ . Next, all higher-order WG modes were terminated with matched loads (Section II-B) resulting in the 11-port  $S$ -matrix  $S^{WG}$ . This matrix was then used in the HB co-simulation setup, as depicted in Fig. 9. Controlling the outward power at the  $TE_{10}$  port provides the WG simulator output power  $P_{WG} = |A_{WG}|^2/2$ . The simulated  $\Gamma_D$  of the AiUC with  $(\theta_s, \varphi_s) = (23.7, 0)^\circ$ , and  $\Gamma_{D1,2}$  of both AiUCs inside the WG simulator are presented in Fig. 10. The results are almost identical at the fundamental frequencies, and only a minor discrepancy is observed at  $2f_0$ . The detailed performance comparison of two models is given below.

### B. WG Simulator Prototype and Measurement Setup

The two-element WG simulator prototype is shown in Fig. 11. The brass base and the WG elements were fabricated by CNC milling; the PCB and all components were mounted using reflow soldering. Gate and drain DC biasing/feeding

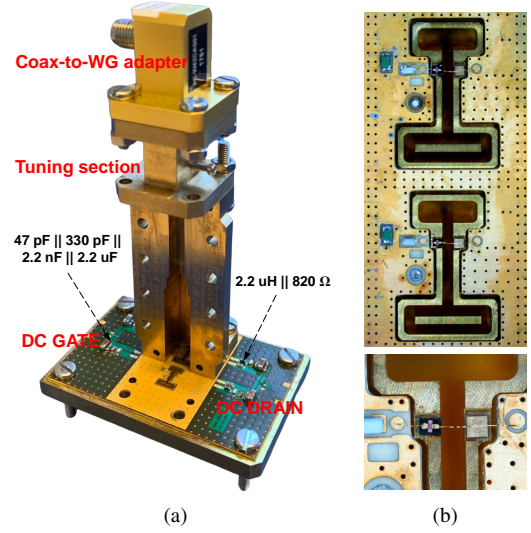


Fig. 11. (a) Assembled two-element active WG simulator (one half is removed for demonstration). (b) Microscope photographs of the assembled AiUCs.

lines were traces to the peripheral PCB area with a bank of 47-pF, 330-pF, 2.2-nF, and 2.2- $\mu$ F capacitors connected in parallel. The parallel combination of a 2.2- $\mu$ H inductor and a 820- $\Omega$  resistor was also introduced in the drain DC circuitry [Fig. 11(a)] for the stabilization and drain current control. The WR-42 interface of the assembly was connected to the measurement equipment through the coaxial-to-WG adapter [Fig. 11(a)]. To compensate for some impedance mismatch of the adapter, which was found to be around  $-18$  dB, we have employed an additional WR-42 section with two tuning screws placed  $\lambda_0/4$  apart [Fig. 11(a)].

First, the small-signal performance, as measured using a vector network analyzer, is demonstrated in Fig. 12. Here we compare the measurement results with the simulated characteristics of the active WG simulator and the AiUC with periodic boundary conditions for  $(\theta_s, \varphi_s) = (23.7, 0)^\circ$ . We have found that the input matching resonance was initially shifted to the higher frequencies by 0.4 GHz. It is believed, and was observed in the simulation model, that the shift was most likely caused by the frequency dispersion and anisotropy of the PCB core laminates. We used an alternative PCB with the length of  $TL_2$  section increased by 150  $\mu$ m. As a result, the frequency shift in  $\Gamma_{in1,2}$  was partly compensated, although at the cost of a relatively weak peak matching level. Finally, the center frequency of the input impedance matching was measured to be around 20.2–20.25 GHz, where the difference between the channels is caused by assembling misalignments. Note that  $\Gamma_{in1(2)} = S_{1,1(2,2)}^m + S_{1,2(2,1)}^m$ , where  $S^m$  is the active WG simulator 3-port  $S$ -matrix as obtained in measurements [Fig. 7(a)]. Additionally, in Fig. 12(a), (b), we have presented transmission coefficients  $S_{WG,1(2)}^m$  of both channels separately to support the similarity of their performance. The measured available gain was computed as  $G_P^c = |S_{WG,1}^m|/\sqrt{1 - |\Gamma_{in1}|^2} + |S_{WG,2}^m|/\sqrt{1 - |\Gamma_{in2}|^2}|^2/2$ . Predictably, both simulation models demonstrate identical results, with the WG simulator 0.2 dB  $G_P^c$  drop due to the dissipative loss in the WG structure. The measured  $G_P^c$

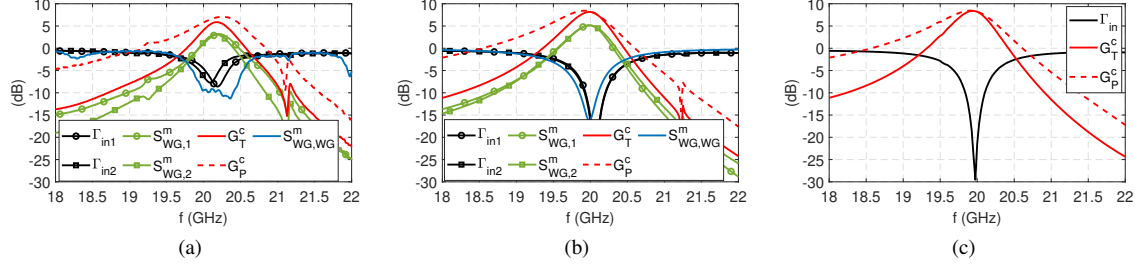


Fig. 12. Comparison of the small-signal performance. (a) Measured and (b) simulated results of the two-element active WG simulator; (c) simulated results of the AiUC in the infinite array environment for  $(\theta_s, \varphi_s) = (23.7, 0)^\circ$ .

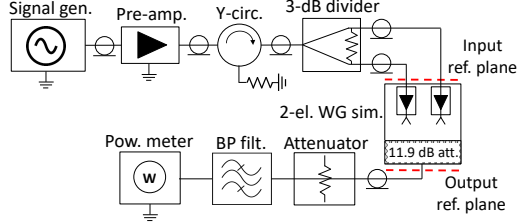


Fig. 13. Two-element active WG simulator large-signal measurement setup.

peak value is 7.2 dB, which is approximately 1 dB lower as compared to the simulation. Likely, the discrepancy is caused by an additional loss of the WG assembly and input coaxial connectors. Another observation is that the optimum  $\Gamma_D$  was realized also at higher frequencies, which is indicated by the peak  $G_P^C$  occurring at 20.25 GHz [Fig.12(a)]. The authors believe that this is due to the WG simulator manufacturing and assembling tolerances.

The WG simulator large-signal performance was measured using the setup in Fig. 13. It was found that the coaxial-to-WG adapter does not realize an acceptable impedance matching at harmonic frequencies. To be sure that the adapter will not disturb  $\Gamma_D$  at harmonics, we introduced an attenuating segment at the output of the WR-42 section (Fig. 8). The attenuator was cut from MAST mf22-0009 foam absorber. Fig. 14 shows a good agreement between the measured and simulated performance.

## V. RESULTS DISCUSSION

Table I compares the proposed AiUC to the previously reported designs, where at least two amplifying AiAs have been employed. The row “element peak available gain” is defined according to (1) and describes the power amplification performance of the element. When the PA and the radiating element can be characterized separately, e.g. [3], [17], this value equals to the PA gain multiplied by antenna radiation efficiency. When the latter is not reported, only PA gain is given as for [16]. The row “peak active gain” considers both PA and radiating element (or array) gains. For the AiUC, this value equals maximum gain ASEP (Fig. 6). The proposed AiUC co-design approach was found computationally efficient and accurate. It naturally includes array mutual coupling effects and integrated PA behaviour, whereas other methods are either based on a separate radiator and PA design [3], [16] or require a multi-element structure full-wave simulation

[17], [19], [20]. Previously, a somewhat similar approach was demonstrated in [32] where the co-simulation of the active reflectarray unit cell was considered. However, their analysis was limited to the broadside operation regime.

Summarizing the results, we can see that the proposed AiUC is capable of high-power generation with high efficiency at mm-wave frequencies. This performance is realized owing to the high radiation efficiency of the antenna element along with the direct impedance matching. Also, the AiUC demonstrates a relatively wide-angle beam-steering performance, though with a relatively narrow bandwidth, as typical for many AiAs. This is mainly due to poor input HEMT matching and resonant impedance behaviour of the radiating element. The first issue should not be considered as a limiting factor of the AiUC design, as a wideband input matching circuitry can be further implemented together with active components in the MMIC technology. The second factor is more critical, as for improved bandwidth, the antenna element should provide a wideband compensation of a relatively high drain reactance while maintaining almost constant input resistance. At the same time, the EM analysis evidences that inside the targeted bandwidth the radiating slot element behaves as a series resonant circuit, which makes it impossible to realize a wideband optimum loading for the capacitive HEMT drain. Thus, achieving a wide AiUC bandwidth ideally should be addressed through the initial co-design of both radiating and active elements.

## VI. CONCLUSION

The developed amplifying active integrated unit cell (AiUC) offers high mm-wave power generation capabilities with the peak output power of 33 dBm and maximum drain efficiency of 47% at K-band. This design is capable of providing a wide-angle  $\pm 60^\circ$  beam-steering range in the E-plane and  $\pm 37^\circ$  range in the H-plane with the transducer gain scan loss below 2.1 dB and drain efficiency above 25% for the 2.5-dB gain compression regime. This result represents a significant improvement over the previously reported designs in terms of the combination of high power efficiency and wide scan range at these frequencies. The main direction of improvement is the relative bandwidth (a few percent in the present case) that is believed can be realized through an initial wideband MMIC PA and radiating element co-design. In this context, the optimum custom impedance at the radiator-PA interface can be found to maximize the bandwidth.

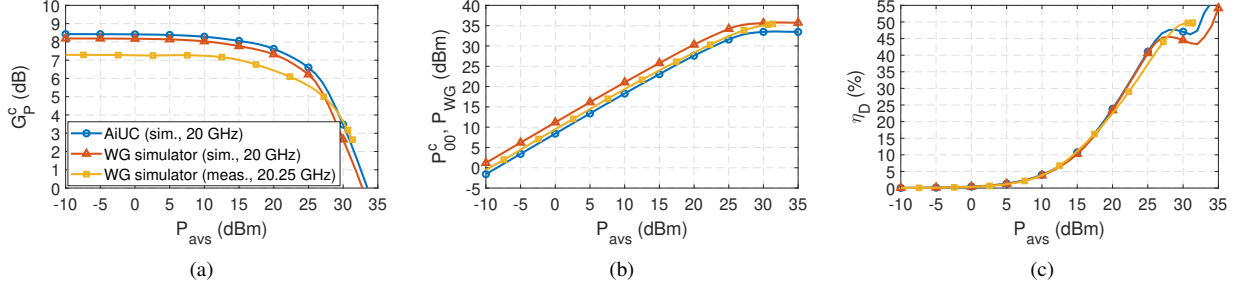


Fig. 14. Comparison of the large-signal performance for the AiUC in the infinite array environment  $(\theta_s, \varphi_s) = (23.7, 0)^\circ$  and two-element active WG simulator: (a) co-polarized available power gain, (b) co-polarized AiUC radiated and WG simulator output powers, (c) drain efficiency.

The proposed AiUC co-design approach has been successfully validated experimentally using the active WG simulator technique; the latter has been extended from its conventional formulation for passive array elements to the case of arrays comprising AiUCs. This represents an important result for designers of active integrated arrays with demanding performance requirements, where the antenna elements mutual coupling and non-linear effects of active electronics play a critical role in the overall system performance.

Future work will extend the proposed methodology to advanced beamforming scenarios where the AiUCs excitation may differ from the considered uniform amplitude distribution (e.g., tapered or MIMO array cases). The corresponding approach is based on the AiUCs mutual coupling analysis [27].

## APPENDIX A

In this study, we use the E-filed Floquet modal functions represented in the following normalized form:

$$\mathbf{E}_{mn}^{TE}(x, y) = \frac{\mathbf{x}^0 k_{ym} - \mathbf{y}^0 k_{xm}}{\sqrt{SY_{mn}^{TE} k_{\perp mn}}} e^{-jk_{xm}x - jk_{ym}y}, \quad (\text{A.1})$$

$$\mathbf{E}_{mn}^{TM}(x, y) = \frac{\mathbf{x}^0 k_{xm} + \mathbf{y}^0 k_{ym}}{\sqrt{SY_{mn}^{TM} k_{\perp mn}}} e^{-jk_{xm}x - jk_{ym}y}, \quad (\text{A.2})$$

$$Y_{mn}^{TE} = k_{zmn}/(\omega\mu), \quad Y_{mn}^{TM} = \omega\epsilon/k_{zmn}, \quad (\text{A.3})$$

$$k_{xm} = k_{x0} + 2\pi m/d_x, \quad k_{ym} = k_{y0} + 2\pi n/d_y, \quad (\text{A.4})$$

$$k_{x0} = k \sin(\theta_s) \cos(\varphi_s), \quad k_{y0} = k \sin(\theta_s) \sin(\varphi_s), \quad (\text{A.5})$$

where  $k$  is the free-space wavenumber;  $\omega$  is the angular frequency;  $k_{\perp mn}$  and  $k_{zmn}$  are the transverse and longitudinal wavenumbers, respectively [22];  $\epsilon, \mu$  are permittivity and permeability of the free space. The H-field modal functions are defined as  $\mathbf{H}_{mn}^{TE/TM} = Y_{mn}^{TE/TM} \mathbf{z}^0 \times \mathbf{E}_{mn}^{TE/TM}$ . Using introduced equivalent surface currents (see Section III-A), the far field can be represented through the wave potentials  $\mathbf{A}, \mathbf{F}$  [26]. After some straightforward but routine mathematical operations, we arrive at the representation (4), where the coefficients  $\mathbf{C}_{mn}^{TE/TM}$  have the following forms:

TABLE I  
PERFORMANCE COMPARISON OF DIFFERENT TRANSMITTING AMPLIFYING AIAA ELEMENTS

	[3]	[17]	[16]	[19]	[20]	This work
Configuration	2 × 2 array	1 × 5 linear array	2 × 2 sub-array	1 × 2 linear array	1 × 2 linear array	AiUC (infinite array)
Implementation	PCB + GaAs pHEMT; 50-Ω match; 1-stage PA, class-E	PCB + AlGaAs pHFET; 50-Ω match; 1-stage PA, class-A	GaAs MMIC; 50-Ω match; 3-stage PA, class-AB	PCB + HJ-FET; direct imp. match; 1-stage PA, class-A	PCB + HJ-FET; amplifier-circuit-antenna concept; 1-stage PA, class-A	PCB + metal base + GaN HEMT; direct imp. matching; 1-stage PA, class-AB
$f_0$ , GHz	2	10	44	10	5	20
Bandwidth, % (criterion)	22.6 ( $\eta_D \geq 55\%$ ) 13.3 (3-dB $G_T$ )	2 ( $ S_{11}  \leq -10$ dB)	Not available	Not available	2.5 ( $ S_{11}  \leq -10$ dB)	4.1, 2.6 (3-dB $G_P, G_T$ ) 1.6 ( $ \Gamma_{in}  \leq -10$ dB)
El. peak av. gain, dB	14	8.9	19.5 (PA)	11.5	10	8.4
Peak active gain, dBi	27.5 (2 × 2 array)	15.8 (1 × 5 array)	Not available	21 (1 × 2 array)	18.9 (1 × 2 array)	14.2 (single AiUC)
Element sizes, $\lambda_0^2$	0.58 × 0.77	0.8 × 1.35	0.51 × 0.51	0.67 × 0.5	0.33 × 0.83	0.62 × 0.51
Max. radiated power/el., dBm	21.5	Not available	9	Not available	2	33
$P_{1dB}$ , dBm	8.5	Not available	-11.5	Not available	-11	21
Peak drain efficiency, %	71.35 (6 dB compression)	Not available	21.5 (3 dB compression)	Not available	20.5 (1 dB compression)	47 (2.5 dB compression)
Beam-steering implementation	No (fixed beam)	No (fixed beam)	Integrated phase shifters	Varactor-tuning	Gate bias variation	External phase shifters
Trans. gain $G_T$ scan loss and dr. eff. $\eta_D$	Not applicable	Not applicable	1.5 dB $G_T$ scan loss	2 dB $G_T$ scan loss	Not available	2.1 dB $G_T$ scan loss, $\eta_D \geq 25\%$
Beam-steering range	Not applicable	Not applicable	±26°, 2D	From -14 to +10°, 1D	From +26 to +30°, 1D	2D: ±60°, E-plane; ±37°, H-plane

$$C_{\theta mn}^{TE}(\theta, \varphi) = -j \frac{\cos(\theta)k_{zmn} + k}{k_{\perp mn} \sqrt{SY_{mn}^{TE}}} \times (\sin(\varphi)k_{xm} - \cos(\varphi)k_{yn}), \quad (\text{A.6})$$

$$C_{\varphi mn}^{TE}(\theta, \varphi) = -j \frac{k_{zmn} + \cos(\theta)k}{k_{\perp mn} \sqrt{SY_{mn}^{TE}}} \times (\cos(\varphi)k_{xm} + \sin(\varphi)k_{yn}), \quad (\text{A.7})$$

$$C_{\theta mn}^{TM} = -C_{\varphi mn}^{TE}, \quad C_{\varphi mn}^{TM} = C_{\theta mn}^{TE}. \quad (\text{A.8})$$

## APPENDIX B

To relate the transmission coefficient of the WG simulator to the AiUC gains (1), we can represent the TE<sub>10</sub> WG mode as the superposition of two plane waves:

$$\mathbf{E}_{WG10}^{TE}(x) = \mathbf{y}^0 A_{WG} \frac{\cos(k_{WGx}x)}{\sqrt{Y_{WG10}^{TE} S}} = \mathbf{y}^0 A_{WG} \frac{\exp(-jk_{WGx}x) + \exp(jk_{WGx}x)}{2\sqrt{Y_{WG10}^{TE} S}}, \quad (\text{B.1})$$

$$Y_{WG10}^{TE} = \frac{\sqrt{k^2 - k_{WGx}^2}}{\omega\mu}, \quad k_{WGx} = \pi/(2d_x). \quad (\text{B.2})$$

Each term of (B.1) can be recognized as the Floquet TE<sub>00</sub> modal function (A.1) with amplitude  $A_{00}^{TE} = \mp A_{WG}/2$  and  $\theta_s = \pm\theta_s^{WG}$ . Next, from (11) we can find the amplitude of the incident AiUC wave exciting each Floquet mode:

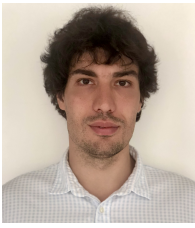
$$A_{Fl} = A_1/(2 \cos(kd_x \sin(\theta_s^{WG})/2)). \quad (\text{B.3})$$

Finally, substituting (10) into (B.3) and recalling definitions (1) we arrive at (12).

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